

S.V. National Institute of Technology, Surat B.Tech. II (EC), 3rd Semester Mid Semester Exam, September-2014 Electronic Devices and Circuits (EC201)

Marks: 30 Time: 01Hours

Instructions:

- 1. Attempt all questions.
- 2. Draw neat and clean circuit diagram/block diagram and waveforms.
- 3. Maintain the Sequence of Answer.
- 4. Assume data if necessary with proper justification.

Q.1 Attempt Any One:

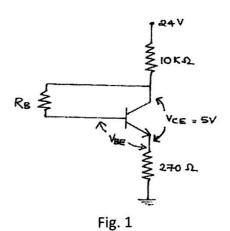
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- (a) List out the different types of biasing methods in BJT. Draw the circuit diagram of fixed bias circuit and derive the equations for all necessary parameters.
- (b) Draw the AC equivalent of Common Drain configuration. And derive the equation 06 for voltage gain, input impedance and output impedance.

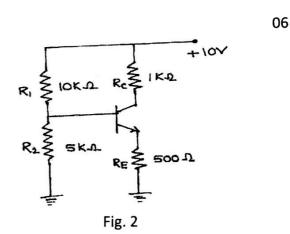
Q.2 Attempt Any Two:

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(a) A transistor with β =45 is used with collector to base resistor RB biasing with quiescent value of 5V for VCE. If VCC=24V, RC=10k Ω , RE=270 Ω , find the value of RB (Fig. 1).

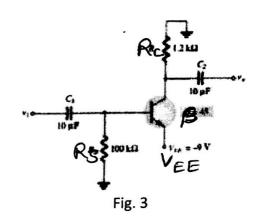


(b) For the circuit shown in figure, determine the value of IC and VCE. Assume VBE=0.7V and β =100 (Fig. 2).



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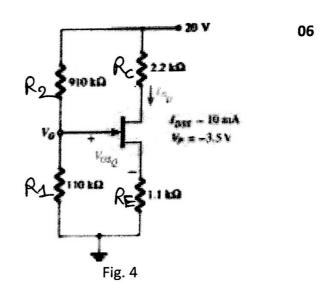
(c) Determine V_C and V_B for the circuit diagram shown in Fig. 3.



Q.3 For the network given in Fig. 4, determine : (i) I_{DQ} , V_{GSQ} (ii) V_{G} , V_{D} , V_{S} (iii)Voltage Gain (iv)Input Impedance (v)Output Impedance

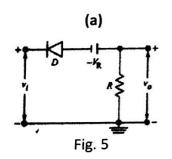
$$R_1 = 110 \text{ k}$$

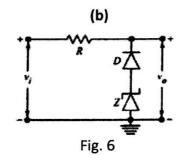
 $R_2 = 910 \text{ k}$
 $R_c = 2.2 \text{ k}$
 $R_c = 1.1 \text{ k}$
 $R_{\text{E}} = 1.1 \text{ k}$
 $R_{\text{DSS}} = -10 \text{ mA}$
 $V_{\text{P}} = -3.5 \text{ V}$
 $V_{\text{P}} = -20 \text{ V}$

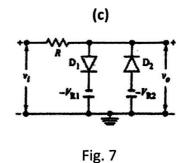


Q.4 Attempt any Two: (Each 03 marks):

For the circuit shown in following Figures explain the working of the circuit, draw the output voltage and the transfer characteristics. In each case assume $V_{\gamma}=0$, Rf=0 and Rr= ∞ .







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